

OX4170A-D3-2-25.000-3.3

Rohis

ELECTRICAL SPECIFICATIONS

PARAMETER	SYMBOL	CONDITION	VALUE		UNIT	
			Min.	Тур.	Max.	
Nominal Frequency	fo			25.000		MHz
Supply Voltage	Vs	Vs ±5% @ 25°C	3.135	3.3	3.465	V
Lu su t Dourse	Ps	Steady state, @ 25°C			350	mW
Input Power	P _{S,w}	During warm-up ,@ 25°C			900	mW
Warm-up Time	tw	Vs, Ta=+25°C, within ±100ppb of final frequency with reference after 1 hour on			3	min
Frequency Calibration	$\Delta f/f_0$	Ta=+25°C, after 15mins power on ref. to nominal frequency	-500		+500	ppb
Frequency Stability vs. Temperature	$\Delta f/f_0$ (T _a)	Ta= $-40^{\circ}C+85^{\circ}C$, measurement referenced to $25^{\circ}C$	-20		+20	ppb
Frequency Stability vs. Supply Voltage	$\Delta f/f_0 (\Delta V_{CC})$	Ta=25°C, Vs±5%, load=15pF	-10		+10	ppb
Frequency Stability vs. Load Variation	$\Delta f/f_0$ (Δl)	Ta=25°C, Vs, load=15pF±5%	-10		+10	ppb
Aging, after 30 days of operation	$\Delta f / \Delta t_d$	Daily	-2.0	±1.0	+2.0	ppb
Operating Temperature	Ta		-40		+85	°C
Storage Temperature	T(stg)	Absolute max	-40		+105	°C



OX4170A-D3-2-25.000-3.3

PHASE NOISE

PARAMETER	SYMBOL	CONDITION	VALUE			UNIT
			Min.	Тур.	Max.	
@10 Hz Offset	£ (∆f)			-90	-85	dBc/Hz
@100 Hz Offset	£ (∆f)			-122	-115	dBc/Hz
@1 kHz Offset	£ (∆f)			-146	-140	dBc/Hz
@10 kHz Offset	£ (∆f)			-158	-155	dBc/Hz
@100 kHz Offset	£ (∆f)			-160	-158	dBc/Hz
@1 MHz Offset	£ (∆f)			-163	-160	dBc/Hz

CMOS OUTPUT CHARACTERISTICS

PARAMETER	SYMBOL	CONDITION	VALUE			UNIT
			Min.	Тур.	Max.	
Output Levels	VOH/VOL	V _{CC} = 3.3V, load = 15pF		3.0/0.3		V
Duty Cycle	DC	load = 15pF		45/55		%
Load				15		pF

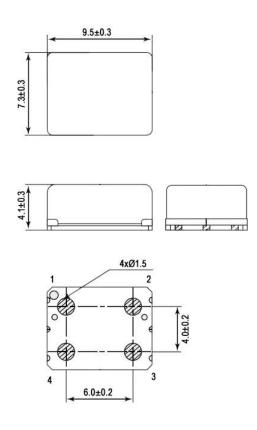
ENVIRONMENTAL MECHANICAL CONDITIONS

Storage temperature range	-40°C to +105°C
Drop Test	The test shall be carried out as the provisions of the IEC60028-2-32 test Ed. 10cm height, 3 times on hard board with thickness of 3cm
Bumping Test	Device are bumped to three mutually perpendicular axes at peak acceleration of 400m/s ² , each 4000±10times, 6ms pulse duration time
Vibration Test	Frequency range: 1Hz-4Hz-100Hz-200Hz Acceleration: 0.0001g ² /Hz-0.01g ² /Hz-0.001g ² /Hz Grms=1.15g Sweep time: 30 minutes (perpendicular axes each sweep time)
Mechanical Shock	100g, 6mS duration, 1/2 sine wave, 3 shocks each direction along 3 mutually perpendicular planes.
Thermal shock	0.5h@-40 $^{\circ}$ C , 0.5h@+85 $^{\circ}$ C , Note: the changing time < 30 seconds, cycling for 100 times



OX4170A-D3-2-25.000-3.3

MECHANICAL DIMENSIONS AND PIN FUNCTIONING



PIN	SYMBOL	FUNCTION
1	N/C	No connect
2	GND	Ground
3	OUTPUT	Output
4	Vcc	Supply Voltage

RALTRON		Signed	Date
Created		СР	July 22, 2019
Eng. approved		SP	July 22, 2019
REV A	Original Release		
В	CP, September 05, 2019		

Raltron Electronics / RAMI Technology USA, LLC, including its affiliates, employees, agents and other persons acting on its behalf (collectively Raltron/RAMI Tech), disclaim any and all liability for any errors or inaccuracies contained in this data sheet. While Raltron/RAMI Tech has made every reasonable effort ensure the accuracy of all product information, specifications and data contained herein, Raltron/RAMI Tech has made every reasonable effort ensure the accuracy of all product information, specifications and data contained herein, Raltron/RAMI Tech does not guarantee that the information is accurate, reliable or current. The product information is provided only for reference purposes only and is subject to change, correction or revision, at any time without notice. Raltron/RAMI Tech does not assume any liability arising out of an application or use of any product described herein and disclaims any warranties expressed or implied. The user of products in such applications shall assume all risks of such use and will agree to hold Raltron/RAMI Tech, harmless against all damages.

Copyright © 2016, Raltron Electronics / RAMI Technology USA, LLC. All rights reserved. No part of this document may be reproduced in any form without the prior written permission of Raltron Electronics / RAMI Technology USA, LLC.